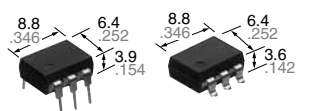


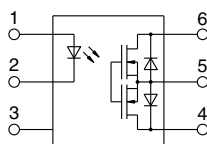
**Normally closed type
with reinforced insulation**

**PhotoMOS®
GE 1 Form B
(AQV41○EH)**



(Height includes standoff)

mm inch



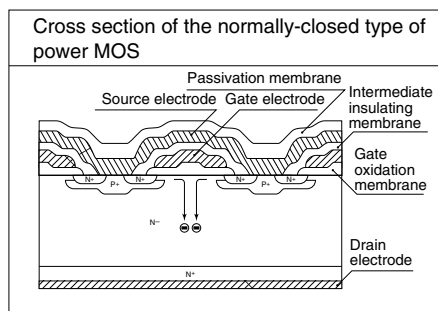
RoHS compliant

FEATURES

- 1 Form B output type**
- 2. 60V type couples high capacity (0.55A) with low on-resistance (Typ. 1Ω).**

3. Low on-resistance

This has been realized thanks to the built-in MOSFET processed by our proprietary method, DSD (Double-diffused and Selective Doping) method.



4. Controls low-level analog signals

PhotoMOS feature extremely low closed-circuit offset voltage to enable control of low-level analog signals without distortion.

5. High sensitivity and low on-resistance

Can control max. 0.55 A load current with 5 mA input current.

Low on-resistance of Typ. 1Ω (AQV412EH).

6. Low-level off-state leakage current

7. Reinforced insulation: 5,000 V

More than 0.4 mm internal insulation distance between inputs and outputs. Conforms to EN41003, EN60950 (reinforced insulation).

TYPICAL APPLICATIONS

- Power supply
- Measuring equipment
- Security equipment
- Telephone equipment
- Sensing equipment

TYPES

	I/O isolation voltage	Output rating*		Package	Part No.				Packing quantity		
					Through hole terminal	Surface-mount terminal					
		Load voltage	Load current						Tube packing style		Tape and reel packing style
						Picked from the 1/2/3-pin side	Picked from the 4/5/6-pin side				
AC/DC dual use	5,000 Vrms (Reinforced)	60 V	550 mA	DIP6-pin	AQV412EH	AQV412EHA	AQV412EHAX	AQV412EHAZ	1 tube contains: 50 pcs.	1,000 pcs.	
		350 V	130 mA		AQV410EH	AQV410EHA	AQV410EHAX	AQV410EHAZ	1 batch contains: 500 pcs.		
		400 V	120 mA		AQV414EH	AQV414EHA	AQV414EHAX	AQV414EHAZ			

*Indicate the peak AC and DC values.

Note: The surface mount terminal shape indicator "A" and the packing style indicator "X" or "Z" are not marked on the device.

RATING

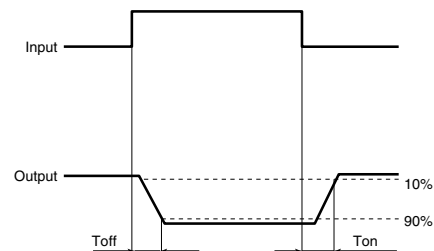
1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

Item		Symbol	Type of connection	AQV412EH(A)	AQV410EH(A)	AQV414EH(A)	Remarks
Input	LED forward current	I _F		50 mA			f = 100 Hz, Duty factor = 0.1%
	LED reverse voltage	V _R		5 V			
	Peak forward current	I _{FP}		1 A			
	Power dissipation	P _{in}		75 mW			
	Load voltage (peak AC)	V _L		60 V	350 V	400 V	
Output	Continuous load current	I _L	A	0.55 A	0.13 A	0.12 A	A connection: Peak AC, DC B,C connection: DC
			B	0.65 A	0.15 A	0.13 A	
			C	0.8 A	0.17 A	0.15 A	
	Peak load current	I _{peak}		1.5 A	0.4 A	0.3 A	A connection: 100 ms (1 shot), V _L = DC
	Power dissipation	P _{out}		500 mW			
Total power dissipation		P _T		550 mW			
I/O isolation voltage		V _{iso}		5,000 Vrms			
Ambient temperature	Operating	T _{opr}		-40 to +85°C -40 to +185°F			(Non-icing at low temperatures)
	Storage	T _{stg}		-40 to +100°C -40 to +212°F			

2. Electrical characteristics (Ambient temperature: 25°C 77°F)

Item			Symbol	Type of connection	AQV412EH(A)		AQV410EH(A)		AQV414EH(A)	Condition
Input	LED operate (OFF) current	Typical	I _{Foff}	—	1.9 mA			I _L = Max.		
		Maximum			3.0 mA					
	LED reverse (ON) current	Minimum	I _{Fon}	—	0.4 mA			I _L = Max.		
		Typical			1.8 mA					
	LED dropout voltage	Typical	V _F	—	1.25 V (1.14 V at I _F = 5 mA)			I _F = 50 mA		
Maximum		1.5 V								
Output	On resistance	Typical	R _{on}	A	1 Ω	18 Ω	25.2 Ω	I _F = 0 mA I _L = Max. Within 1 s		
		Maximum			2.5 Ω	35 Ω	50 Ω			
		Typical	R _{on}	B	0.55 Ω	13 Ω	19 Ω	I _F = 0 mA I _L = Max. Within 1 s		
		Maximum			1.3 Ω	17.5 Ω	25 Ω			
		Typical	R _{on}	C	0.3 Ω	6.5 Ω	10 Ω	I _F = 0 mA I _L = Max. Within 1 s		
		Maximum			0.7 Ω	8.8 Ω	12.5 Ω			
	Off state leakage current	Maximum	I _{LLeak}	—	10 μA			I _F = 5 mA V _L = Max.		
Transfer characteristics	Operate (OFF) time*	Typical	T _{off}	—	3 ms	1.5 ms	1.3 ms	I _F = 0 mA → 5 mA I _L = Max.		
		Maximum			8 ms	3.0 ms				
	Reverse (ON) time*	Typical	T _{on}	—	0.3 ms			I _F = 5 mA → 0 mA I _L = Max.		
		Maximum			1.5 ms					
	I/O capacitance	Typical	C _{iso}	—	0.8 pF			f = 1 MHz V _B = 0 V		
		Maximum			1.5 pF					
Initial I/O isolation resistance	Minimum	R _{iso}	—	1.000 MΩ			500 V DC			

*Operate/Reverse time



3. Recommended operating conditions (Ambient temperature: 25°C 77°F)

Please use under recommended operating conditions to obtain expected characteristics.

Item	Symbol	Min.	Max.	Unit
LED current	I_F	5	30	mA
AQV412EH(A)	Load voltage (Peak AC)	V_L	48	V
	Continuous load current (A connection)	I_L	0.55	A
AQV410EH(A)	Load voltage (Peak AC)	V_L	280	V
	Continuous load current (A connection)	I_L	0.13	A
AQV414EH(A)	Load voltage (Peak AC)	V_L	320	V
	Continuous load current (A connection)	I_L	0.12	A

■ These products are not designed for automotive use.

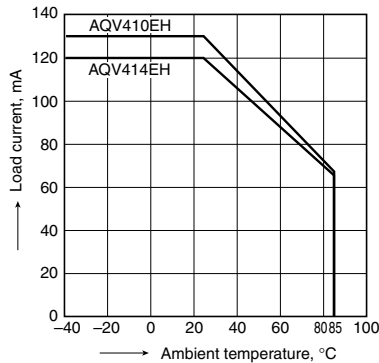
If you are considering to use these products for automotive applications, please contact your local Panasonic Corporation technical representative.

REFERENCE DATA

1-(1). Load current vs. ambient temperature characteristics

Allowable ambient temperature: -40 to $+85^{\circ}\text{C}$
 -40 to $+185^{\circ}\text{F}$

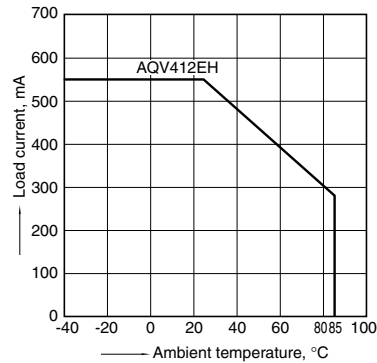
Type of connection: A



1-(2). Load current vs. ambient temperature characteristics

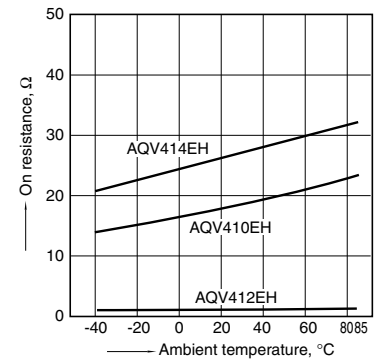
Allowable ambient temperature: -40 to $+85^{\circ}\text{C}$
 -40 to $+185^{\circ}\text{F}$

Type of connection: A



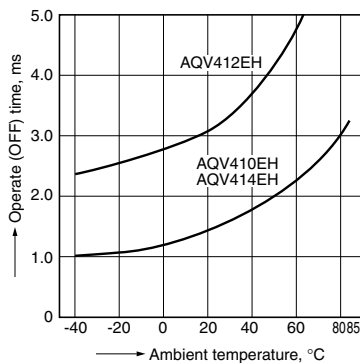
2. On resistance vs. ambient temperature characteristics

Measured portion: between terminals 4 and 6;
 LED current: 0 mA; Load voltage: Max. (DC);
 Continuous load current: Max. (DC)



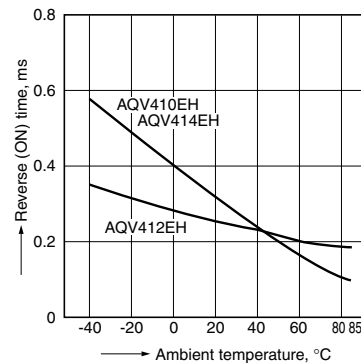
3. Operate (OFF) time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: Max. (DC);
 Continuous load current: Max. (DC)



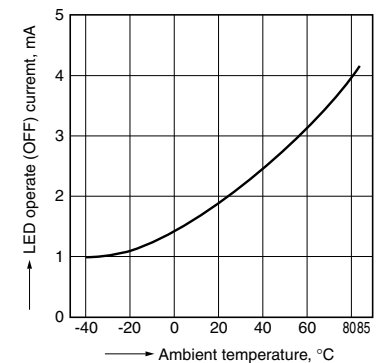
4. Reverse (ON) time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: Max. (DC);
 Continuous load current: Max. (DC)



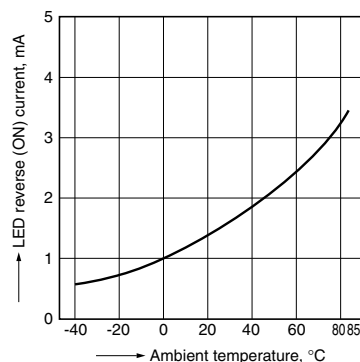
5. LED operate (OFF) current vs. ambient temperature characteristics

Sample: All types;
 Load voltage: Max. (DC);
 Continuous load current: Max. (DC)



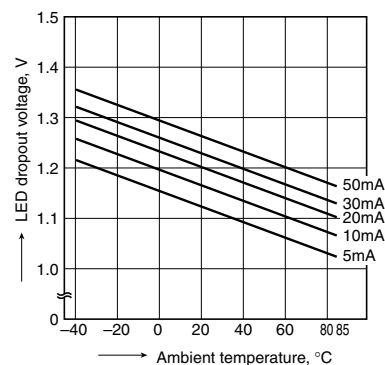
6. LED reverse (ON) current vs. ambient temperature characteristics

Sample: All types;
 Load voltage: Max. (DC);
 Continuous load current: Max. (DC)



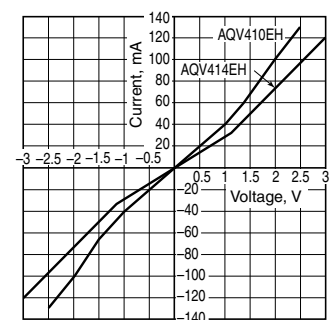
7. LED dropout voltage vs. ambient temperature characteristics

Sample: All types;
 LED current: 5 to 50 mA

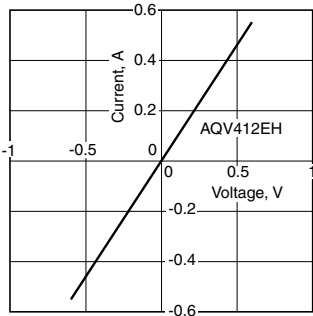


8-(1). Current vs. voltage characteristics of output at MOS portion

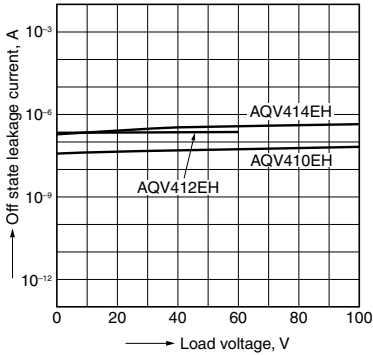
Measured portion: between terminals 4 and 6;
 Ambient temperature: 25°C 77°F



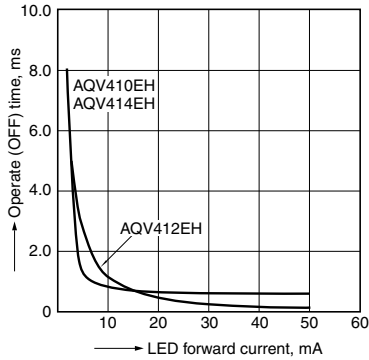
8-(2). Current vs. voltage characteristics of output at MOS portion
Measured portion: between terminals 4 and 6;
Ambient temperature: 25°C 77°F



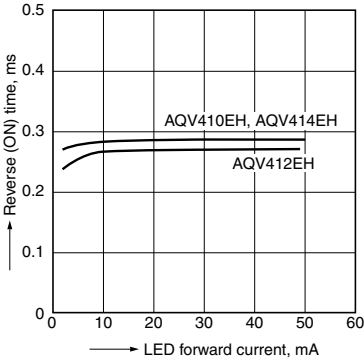
9. Off state leakage current vs. load voltage characteristics
Sample: All types;
Measured portion: between terminals 4 and 6;
LED current: 5 mA; Ambient temperature: 25°C 77°F



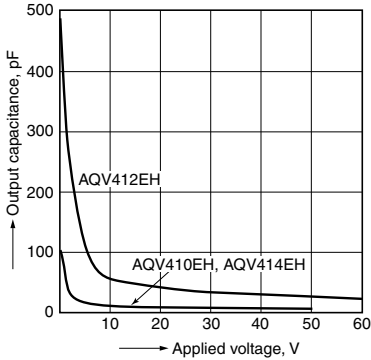
10. Operate (OFF) time vs. LED forward current characteristics
Measured portion: between terminals 4 and 6;
Load voltage: Max. (DC); Continuous load current: Max. (DC); Ambient temperature: 25°C 77°F



11. Reverse (ON) time vs. LED forward current characteristics
Measured portion: between terminals 4 and 6;
Load voltage: Max. (DC); Continuous load current: Max. (DC); Ambient temperature: 25°C 77°F



12. Output capacitance vs. applied voltage characteristics
Measured portion: between terminals 4 and 6;
Frequency: 1 MHz;
Ambient temperature: 25°C 77°F



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